

Description

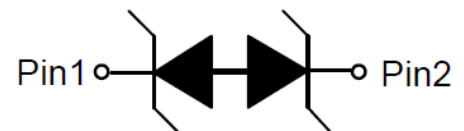
The XE5D3V3B is a bi-directional ESD protection diode designed to protect sensitive electronic components which are connected to low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning. The XE5D3V3B may be used to provide ESD protection up to $\pm 30\text{kV}$ (contact and air discharge) according to IEC61000-4-2, and withstand peak pulse current up to 10A (8/20 μs) according to IEC61000-4-5.

The XE5D3V3B is available in SOD523 package. Standard products are Pb-free and Halogen-free.

<http://www.xihangsemi.com>



SOD523 (Bottom View)



Circuit Diagram

Features

- ◆ Working voltage: 3.3V
- ◆ SOD523 Package
- ◆ Transient protection for data lines to IEC 61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact)
IEC 61000-4-5 (Surge) 10A (8/20 μs)
- ◆ Low leakage current
- ◆ Low clamping voltage
- ◆ Solid-state silicon-avalanche technology



Marking (Top View)

Applications

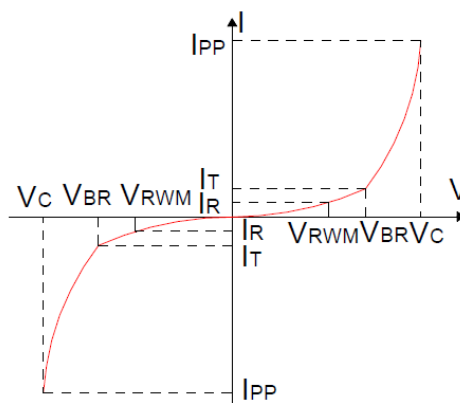
- ◆ Personal digital assistants (PDA's)
- ◆ Notebooks, Desktops, and Servers
- ◆ Cell phone Handsets and Accessories
- ◆ Portable Electronics
- ◆ Peripherals

Order Information

Device	Package	Shipping
XE5D3V3B	SOD523	5000/Tape&Reel

Definitions of electrical characteristics

Symbol	Parameter
V_{RWM}	Reverse Stand-off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Reverse Breakdown Voltage @ I_T
I_R	Reverse Breakdown Current
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}



Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_P = 8/20\mu S$)	P_{PK}	100	W
Peak Pulse Current ($t_P = 8/20\mu S$)	I_{pp}	10	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	kV
ESD according to IEC61000-4-2 contact discharge		± 30	kV
Lead Soldering Temperature	T_L	260 (10 sec)	$^{\circ}C$
Operating Temperature	T_{OP}	-55 to +125	$^{\circ}C$
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$

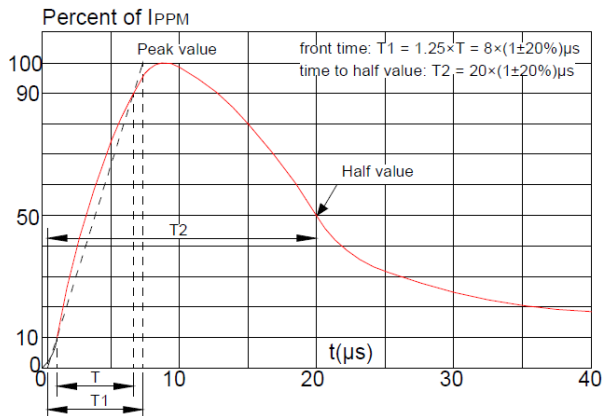
Electrical Characteristics ($T_a=25^{\circ}C$, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Stand-off Voltage	V_{RWM}				± 3.3	V
Reverse Leakage Current	I_R	$V_{RWM} = \pm 3.3V$			100	nA
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	3.7	4.1	5	V
Clamping Voltage ¹⁾	V_{CL}	$I_{PP}=5A \quad t_P = 8/20\mu s$		6	7	V
		$I_{PP}=10A \quad t_P = 8/20\mu s$		8.5	10	V
Junction Capacitance	C_j	$V_R=0V \quad f = 1MHz$		13	15	pF

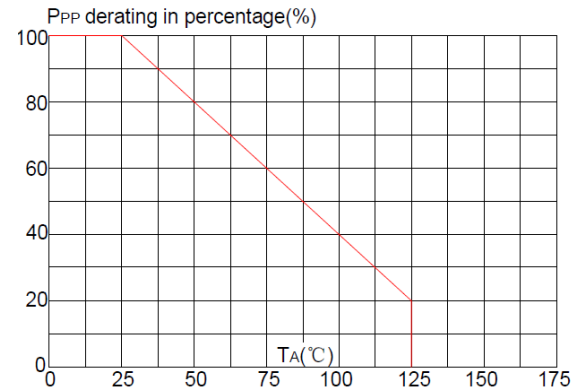
Notes:

1)Non-repetitive current pulse, according to IEC61000-4-5.

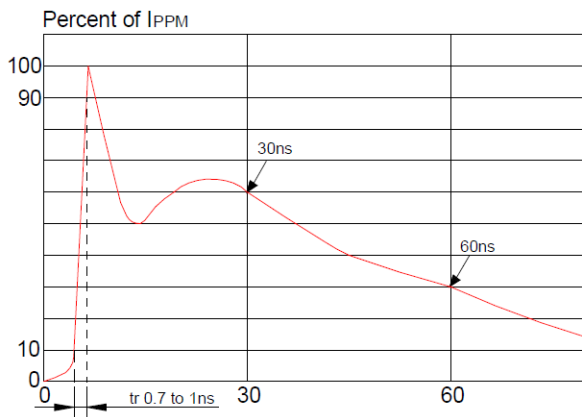
Typical Characteristics (Ta=25℃, unless otherwise noted)



Pulse Waveform (8/20us)

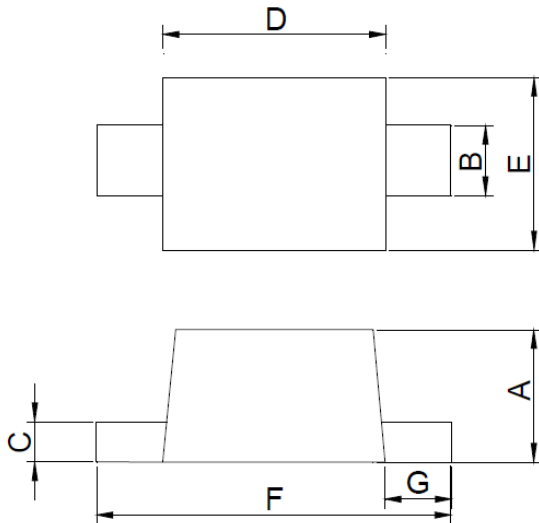


Pulse Derating Curve



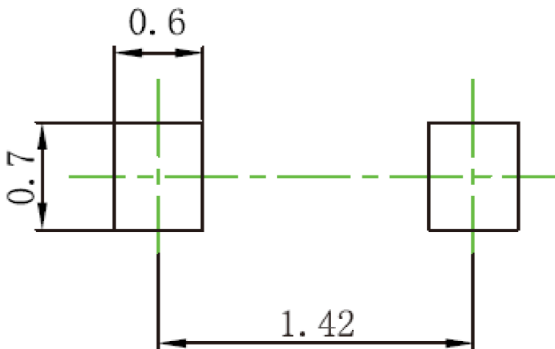
ESD Clamping(8kV Contact Discharge)

Package Outline Dimensions (SOD523)



Dim	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.020	0.028	0.50	0.70
B	0.010	0.014	0.25	0.35
C	0.0028	0.0079	0.07	0.20
D	0.043	0.051	1.10	1.30
E	0.028	0.035	0.70	0.90
F	0.059	0.067	1.50	1.70
G	0.006	0.010	0.15	0.25
P1	0.016		0.40	
P	0.072		1.80	

Recommend Land Pattern (Unit: mm)



Note:

This recommended land pattern is for reference purpose only.

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